



DMP3030SN

P-CHANNEL ENHANCEMENT MODE FIELD EFFECT TRANSISTOR

Features

- Low On-Resistance
- Low Gate Threshold Voltage
- Low Input Capacitance
- Fast Switching Speed
- Lead Free By Design/RoHS Compliant (Note 2)
- ESD Protected Gate
- "Green" Device (Note 4)
- Qualified to AEC-Q101 standards for High Reliability

SC-59

- Compound. UL Flammability Classification Rating 94V-0

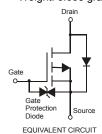
 Moisture sensitivity: Level 1 per J-STD-020C
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Case Material: Molded Plastic, "Green" Molding

- Terminals: Finish Matte Tin annealed over Copper leadframe. Solderable per MIL-STD-202, Method 208
- Terminal Connections: See Diagram
- Marking Information: See Page 3
- Ordering & Date Code Information: See Page 3
- Weight: 0.008 grams (approximate)

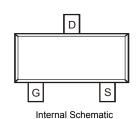






Mechanical Data

Case: SC-59



Maximum Ratings @T_A = 25°C unless otherwise specified

Characteristic	Symbol	Value	Unit
Drain-Source Voltage	V_{DSS}	-30	V
Gate-Source Voltage	V_{GSS}	±20	V
Drain Current (Note 1) Steady State	I _D	-0.7	Α
Pulsed Drain Current (Note 3)	I _{DM}	-2.8	Α

Thermal Characteristics @TA = 25°C unless otherwise specified

Characteristic	Symbol	Value	Unit
Total Power Dissipation (Note 1)	P_d	500	mW
Thermal Resistance, Junction to Ambient	$R_{ hetaJA}$	250	°C/W
Operating and Storage Temperature Range	T _j , T _{STG}	-65 to +150	°C

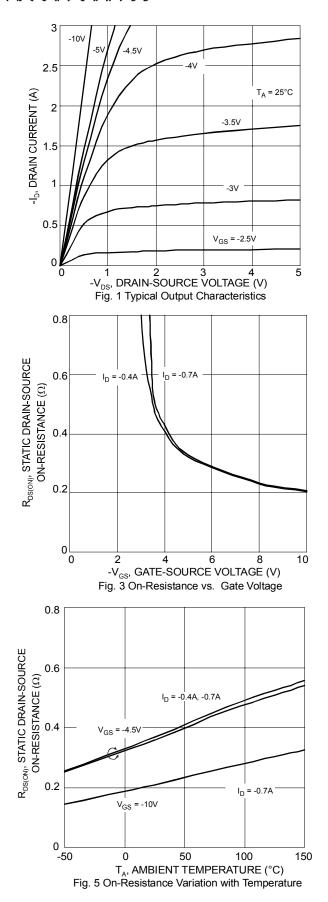
Electrical Characteristics @TA = 25°C unless otherwise specified

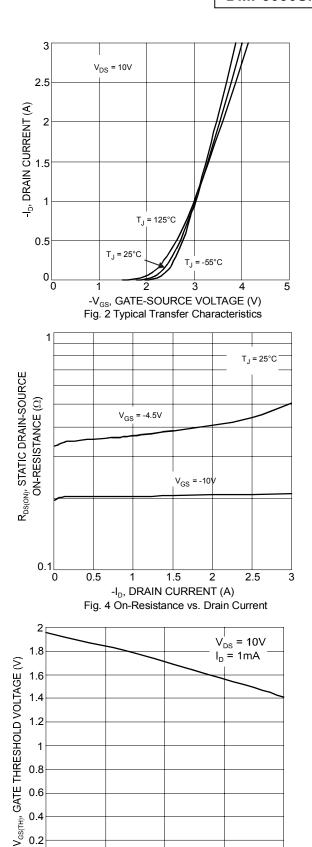
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition		
OFF CHARACTERISTICS (Note 5)								
Drain-Source Breakdown Voltage	BV _{DSS}	-30	_	_	V	$V_{GS} = 0V, I_D = -250mA$		
Zero Gate Voltage Drain Current	I _{DSS}	_	_	-10	μΑ	$V_{DS} = -30V, V_{GS} = 0V$		
Gate-Body Leakage	I _{GSS}	_	_	±10	μА	$V_{GS} = \pm 20V, V_{DS} = 0V$		
ON CHARACTERISTICS (Note 5)			-					
Gate Threshold Voltage	$V_{GS(th)}$	-1.0	_	-3.0	V	$V_{DS} = -10V, I_{D} = -1.0mA$		
Static Drain-Source On-Resistance	R _{DS (ON)}	_	0.20 0.35	0.25 0.45	Ω	V_{GS} = -10V, I_{D} = -0.4A V_{GS} = -4.5V, I_{D} = -0.4A		
Forward Transfer Admittance	Y _{fs}	_	1	_	S	$V_{DS} = -10V, I_D = 0.4A$		
Diode Forward Voltage (Note 5)	V _{SD}	_	-0.8	-1.1	V	$V_{GS} = 0V, I_{S} = -0.7A$		
DYNAMIC CHARACTERISTICS								
Input Capacitance	C _{iss}	_	160	_	pF	V _{DS} = -10V, V _{GS} = 0V -f = 1.0MHz		
Output Capacitance	C _{oss}	_	120	_	pF			
Reverse Transfer Capacitance	C _{rss}	_	50	_	pF	11 - 1.UIVITZ		
SWITCHING CHARACTERISTICS								
Turn-On Delay Time	t _{D(ON)}	_	10	_	ns			
Turn-Off Delay Time	t _{D(OFF)}		25	_	ns	$V_{DD} = -10V, I_{D} = -0.4A,$		
Turn-On Rise Time	t _r		25		ns	V_{GS} = -5.0V, R_{GEN} = 50 Ω		
Turn-Off Fall Time	t _f	_	40	_	ns	1		

Notes:

- 1. Device mounted on FR-4 PCB.
- 2. No purposefully added lead.
- Pulse width ≤10μS, Duty Cycle ≤1%.
- 4. Diodes Inc.'s "Green" policy can be found on our website at http://www.diodes.com/products/lead_free/index.php.
 - . Short duration pulse test used to minimize self-heating effect.









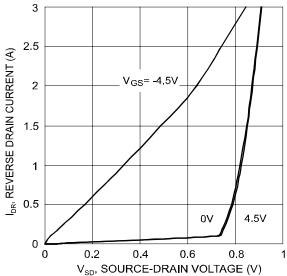
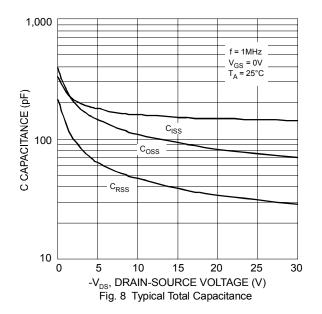


Fig. 7 Reverse Drain Current vs. Source-Drain Voltage

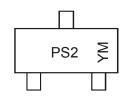


Ordering Information (Note 6)

Part Number	Case	Packaging
DMP3030SN-7	SC-59	3000/Tape & Reel

Notes: 6. For packaging details, go to our website at http://www.diodes.com/datasheets/ap02007.pdf.

Marking Information



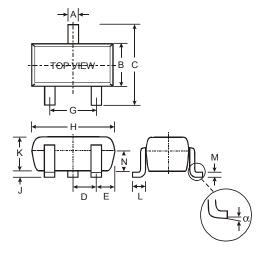
PS2 = Product Type Marking Code

YM = Date Code Marking Y = Year ex: T = 2006 M = Month ex: 9 = September

Date Code Key

Year	200	6	2007		2008	20	09	2010		2011	2	2012
Code	Т		U		V	V	٧	Χ		Υ		Z
Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	0	N	D

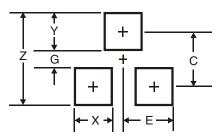
Package Outline Dimensions



SC-59					
Dim	Min	Max			
Α	0.35	0.50			
В	1.50	1.70			
С	2.70	3.00			
D	0.0	95			
E	_	_			
G	1.90				
Н	2.90	3.10			
J	0.013	0.10			
K	1.00	1.30			
L	0.35	0.55			
M	0.10	0.20			
N	0.70	0.80			
α	0°	8°			
All Di	All Dimensions in mm				



Suggested Pad Layout



Dimensions	Value (in mm)
Z	4.0
G	1.2
X	0.9
Υ	1.4
С	2.6
E	0.95

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